Data Sheet No.PD60220

International
IOR Rectifier

IPS031R

FULLY PROTECTED POWER MOSFET SWITCH

Features

- Over temperature shutdown
- Over current shutdown
- Active clamp
- Low current & logic level input
- E.S.D protection

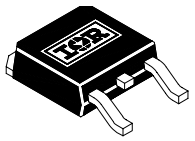
Description

The IPS031R are fully protected three terminal SMART POWER MOSFETs that feature over-current, over-temperature, ESD protection and drain to source active clamp.These devices combine a HEXFET® POWER MOSFET and a gate driver. They offer full protection and high reliability required in harsh environments. The driver allows short switching times and provides efficient protection by turning OFF the power MOSFET when the temperature exceeds 165°C or when the drain current reaches 14A. The device restarts once the input is cycled. The avalanche capability is significantly enhanced by the active clamp and covers most inductive load demagnetizations.

Product Summary

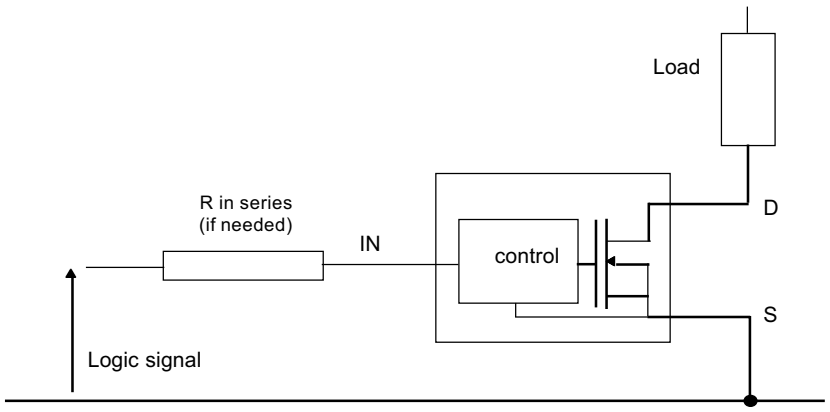
$R_{ds(on)}$	60mΩ (max)
V_{clamp}	50V
$I_{shutdown}$	14A
T_{on}/T_{off}	1.5µs

Package



3-Lead D-Pak

Typical Connection



(Refer to lead assignment for correct pin configuration)

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Absolute Maximum Ratings

Absolute maximum ratings indicate sustained limits beyond which damage to the device may occur. All voltage parameters are referenced to SOURCE lead. ($T_{Ambient}$ = 25°C unless otherwise specified). PCB mounting uses the standard footprint with 70 µm copper thickness.

Symbol	Parameter	Min.	Max.	Units	Test Conditions
V_{ds}	Maximum drain to source voltage	—	47	V	
V_{in}	Maximum input voltage	-0.3	7		
$I_{in,\ max}$	Maximum IN current	-10	+10	mA	
$I_{sd\ cont.}$	Diode max. continuous current (1)			A	
	rth=100°C/W	—	1.6		D-Pak Std footprint
	rth=5°C/W	—	18		D-Pak with Rth=5°C/W
	rth=50°C/W	—	3		D-Pak with sq. footprint
$I_{sd\ pulsed}$	Diode max. pulsed current (1)	—	18		
P_d	Maximum power dissipation(1)			W	
	rth=50°C/W	—	2.5		
	rth=100°C/W	—	1.25		
ESD1	Electrostatic discharge voltage (Human Body)	—	4	kV	C=100pF, R=1500Ω,
ESD2	Electrostatic discharge voltage (Machine Model)	—	0.5		C=200pF, R=0Ω, L=10µH
$T_{stor.}$	Max. storage temperature	-55	150	°C	
T_j max.	Max. junction temperature	-40	+150		
T_{lead}	Lead temperature (soldering, 10 seconds)	—	300		

Thermal Characteristics

Symbol	Parameter	Min.	Typ.	Max.	Units	Test Conditions
R_{th} 1	Thermal resistance with standard footprint	—	100	—	°C/W	D-PAK
R_{th} 2	Thermal resistance with 1" square footprint	—	50	—		
R_{th} 3	Thermal resistance junction to case	—	3	—		

Recommended Operating Conditions

These values are given for a quick design. For operation outside these conditions, please consult the application notes.

Symbol	Parameter	Min.	Max.	Units
$V_{ds\ (max)}$	Continuous drain to source voltage	—	35	V
V_{IH}	High level input voltage	4	6	
V_{IL}	Low level input voltage	0	0.5	
I_{ds} Tamb=85°C	Continuous drain current			A
	TAmbient = 85°C, IN = 5V, rth = 50°C/W, Tj = 125°C) 1" sq. footprint	—	3.3	
	TAmbient = 85°C, IN = 5V, rth = 100°C/W, Tj = 125°C) Std. footprint	—	2	
R_{in}	Recommended resistor in series with IN pin	0.2	5	kΩ
$T_{r\text{-}in(max)}$	Max recommended rise time for IN signal (see fig. 2)	—	1	µS
$F_{r\text{-}Isc}$ (2)	Max. frequency in short circuit condition (Vcc = 14V)	0	1	kHz

(1) Limited by junction temperature (pulsed current limited also by internal wiring)
(2) Operations at higher switching frequencies is possible. See Application. Notes.

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Static Electrical Characteristics

(T_j = 25°C unless otherwise specified.)

Symbol	Parameter	Min.	Typ.	Max.	Units	Test Conditions
$R_{ds(on)}$	ON state resistance T_j = 25°C	20	45	60	mΩ	V_{in} = 5V, I_{ds} = 1A
$R_{ds(on)}$	ON state resistance T_j = 150°C	—	75	100		
I_{dss} @Tj=25°C	Drain to source leakage current	0	0.5	25	µA	V_{cc} = 14V, T_j = 25°C
I_{dss2} @Tj=25°C	Drain to source leakage current	0	5	50		V_{cc} = 40V, T_j = 25°C
V clamp 1	Drain to source clamp voltage 1	47	52	56	V	I_d = 20mA (see Fig.3 & 4)
V clamp 2	Drain to source clamp voltage 2	50	53	60		I_d=$I_{shutdown}$ (see Fig.3 & 4)
$V_{in\ clamp}$	IN to source clamp voltage	7	8.1	9.5		I_{in} = 1 mA
V_{th}	IN threshold voltage	1	1.6	2		I_d = 50mA, Vds = 14V
I_{in}, -on	ON state IN positive current	25	90	200	µA	V_{in} = 5V
I_{in}, -off	OFF state IN positive current	50	130	250		V_{in} = 5V over-current triggered

Switching Electrical Characteristics

V_{cc} = 14V, Resistive Load = 5Ω , Rinput = 50Ω, 100µs pulse,T_j = 25°C, (unless otherwise specified).

Symbol	Parameter	Min.	Typ.	Max.	Units	Test Conditions
T_{on}	Turn-on delay time	0.05	0.3	0.6	µs	See figure 2
T_r	Rise time	0.4	1	2		
T_{rf}	Time to 130% final $R_{ds(on)}$	—	8	—		
T_{off}	Turn-off delay time	0.8	2	3.5		See figure 2
T_f	Fall time	0.5	1.5	2.5		
Q_{in}	Total gate charge	—	11	—	nC	V_{in} = 5V

Protection Characteristics

Symbol	Parameter	Min.	Typ.	Max.	Units	Test Conditions
T_{sd}	Over temperature threshold	—	165	—	°C	See fig. 1
I_{sd}	Over current threshold	10	14	18	A	See fig. 1
V_{reset}	IN protection reset threshold	1.5	2.3	3	V	
T_{reset}	Time to reset protection	2	10	40	µs	V_{in} = 0V, Tj = 25°C
EOI_OT	Short circuit energy (see application note)	—	400	—	µJ	V_{cc} = 14V

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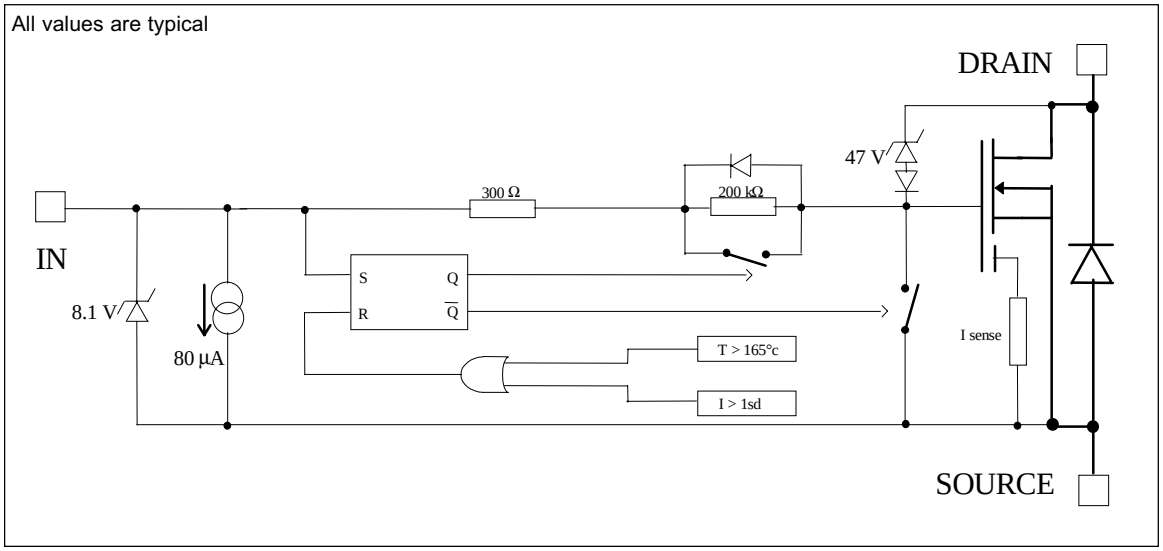
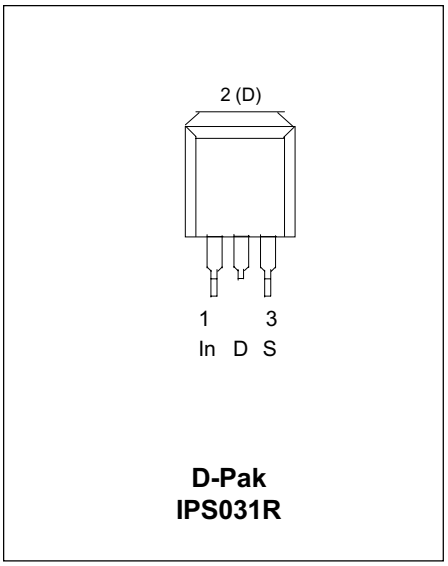
Functional Block Diagram



Lead Assignments



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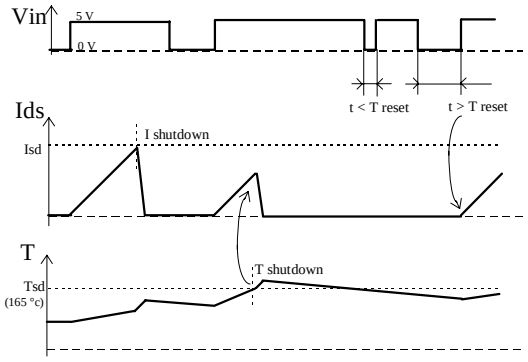

Figure 1 - Timing diagram

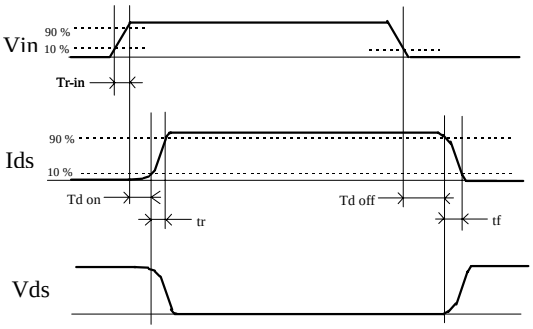

Figure 2 - IN rise time & switching time definitions

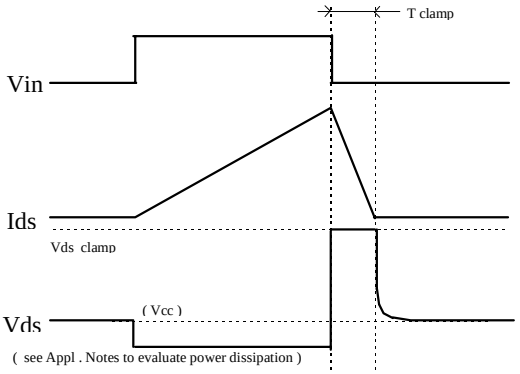

Figure 3 - Active clamp waveforms

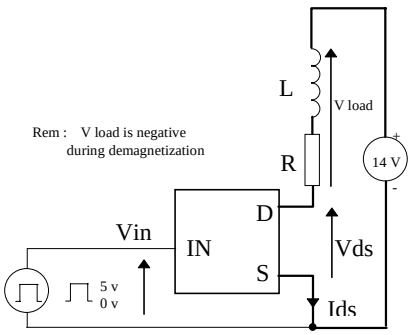

Figure 4 - Active clamp test circuit

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All curves are typical values with standard footprints. Operating in the shaded area is not recommended.

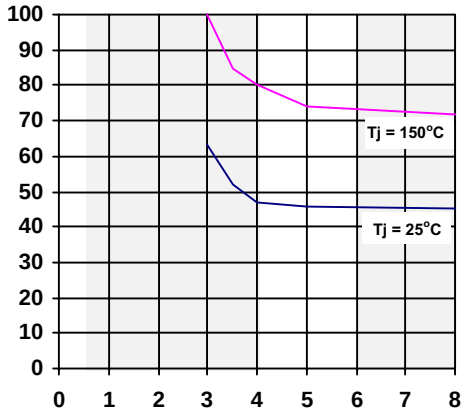

Figure 5 - Rds ON (mΩ) Vs Input Voltage (V)

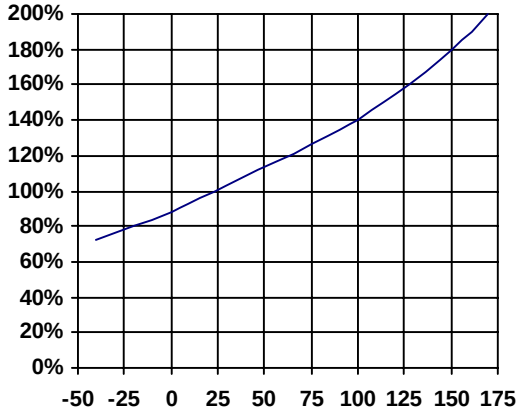

Figure 6 - Normalised Rds ON (%) Vs Tj (°C)

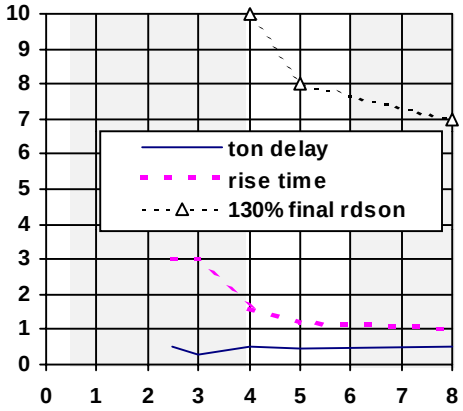

Figure 7 - Turn-ON Delay Time, Rise Time & Time to 130% final $R_{ds(on)}$ (us) Vs Input Voltage (V)

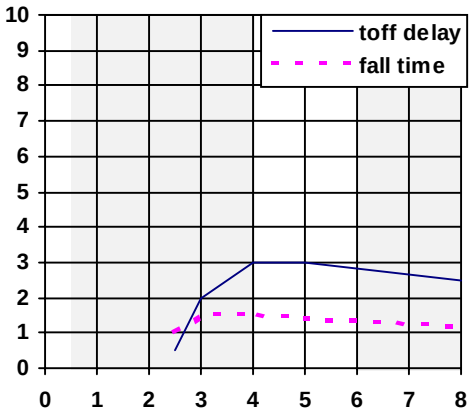

Figure 8 - Turn-OFF Delay Time & Fall Time (us) Vs Input Voltage (V)

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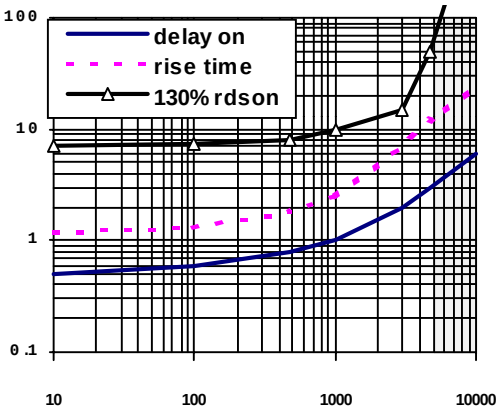

Figure 9 - Turn-ON Delay Time, Rise Time & Time to 130% final $R_{ds(on)}$ (us) Vs IN Resistor (Ω)

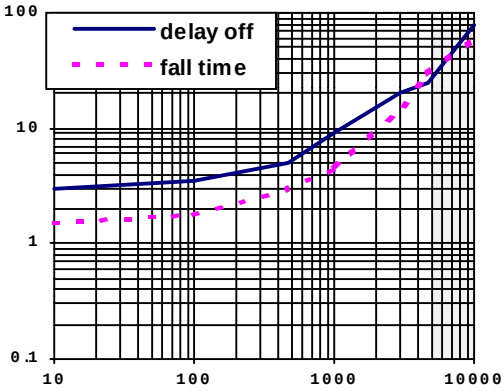

Figure 10 - Turn-OFF Delay Time & Fall Time (us) Vs IN Resistor (Ω)

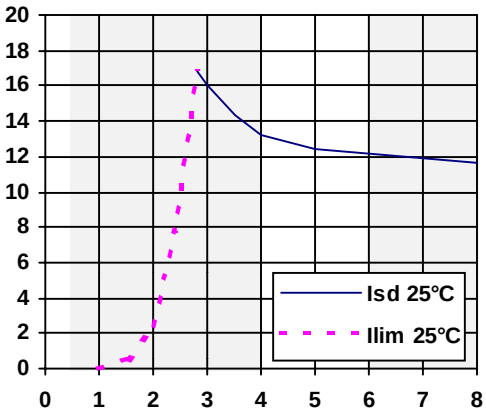

Figure 11 - Current limitation & I shutdown (A) Vs Vin (V)

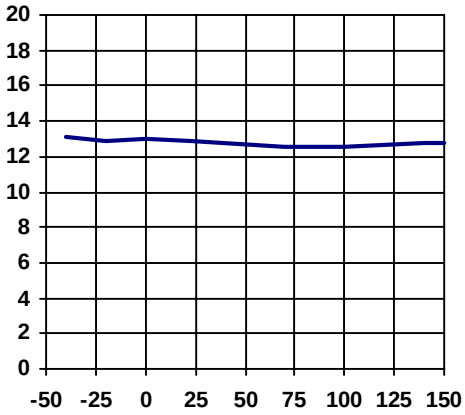

Figure 12 - I shutdown (A) Vs Temperature (°C)

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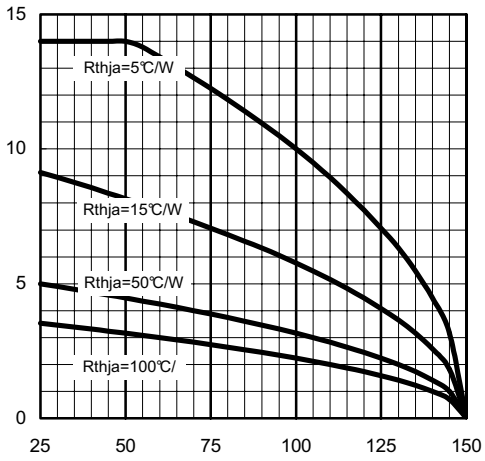

Figure 13 - Max. I load current (A) Vs Tamb (°C)
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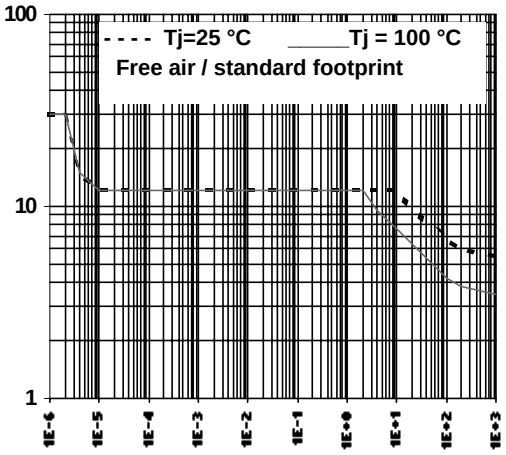

Figure 14 - Ids (A) Vs Protection Resp. Time (s)
IPS031R

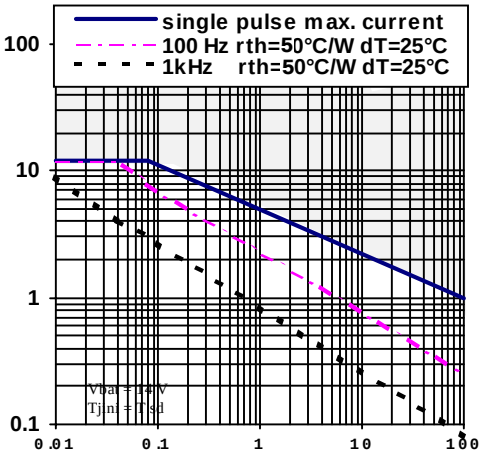

Figure 15 - Iclamp (A) Vs Inductive Load (mH)

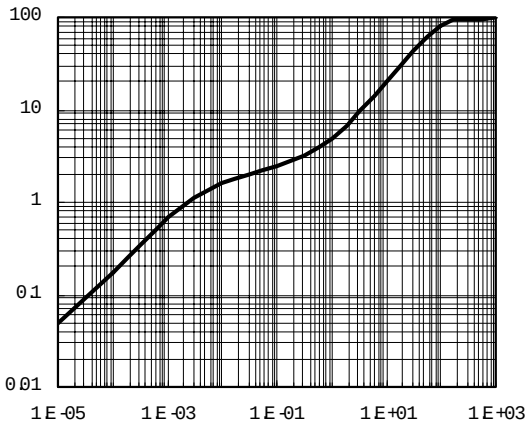

Fig.16 - Transient Thermal Impedance (°C/W)
Vs Time (s) - IPS031R

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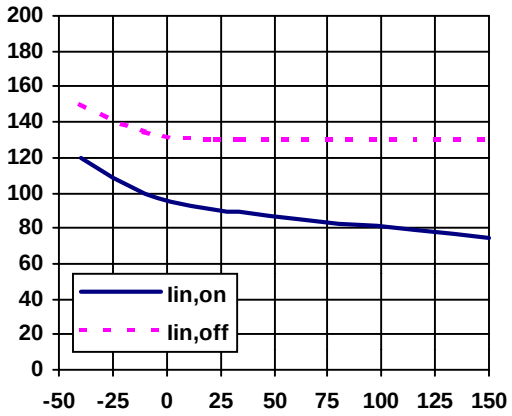

Figure 17 - Input current (µA) Vs Junction (°C)

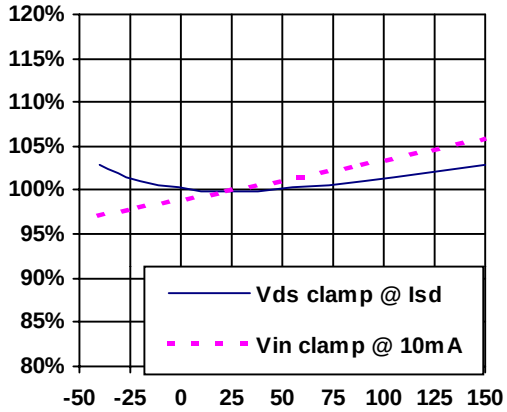

Figure 18 - Vin clamp and V clamp2 (%) Vs Tj (°C)

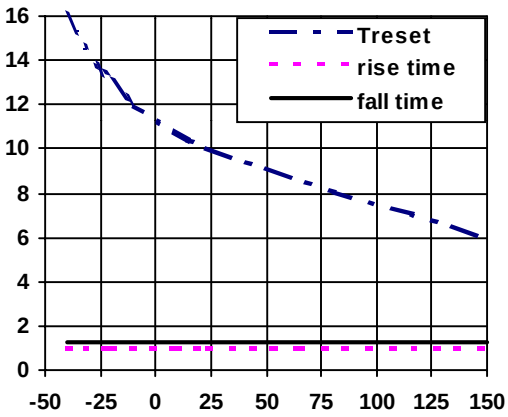

Figure 19 - Turn-on, Turn-off, and treset (µs) Vs Tj (°C)

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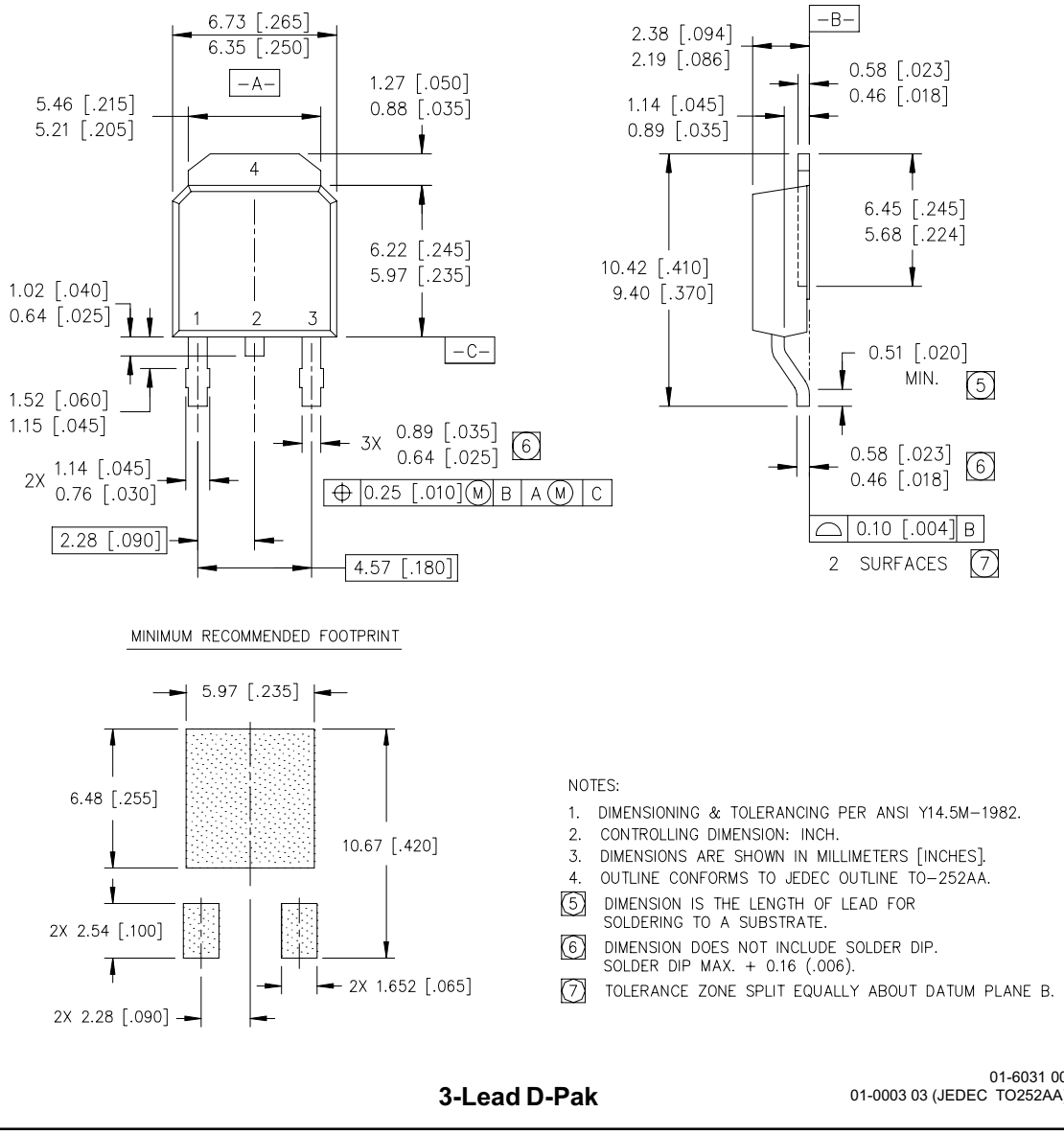
Case Outline



NOTES:

1. DIMENSIONING & TOLERANCING PER ANSI Y14.5M–1982.
2. CONTROLLING DIMENSION: INCH.
3. DIMENSIONS ARE SHOWN IN MILLIMETERS [INCHES].
4. OUTLINE CONFORMS TO JEDEC OUTLINE TO–252AA.

(5) DIMENSION IS THE LENGTH OF LEAD FOR SOLDERING TO A SUBSTRATE.

(6) DIMENSION DOES NOT INCLUDE SOLDER DIP. SOLDER DIP MAX. + 0.16 (.006).

(7) TOLERANCE ZONE SPLIT EQUALLY ABOUT DATUM PLANE B.

3-Lead D-Pak

01-6031 00
01-0003 03 (JEDEC TO252AA)

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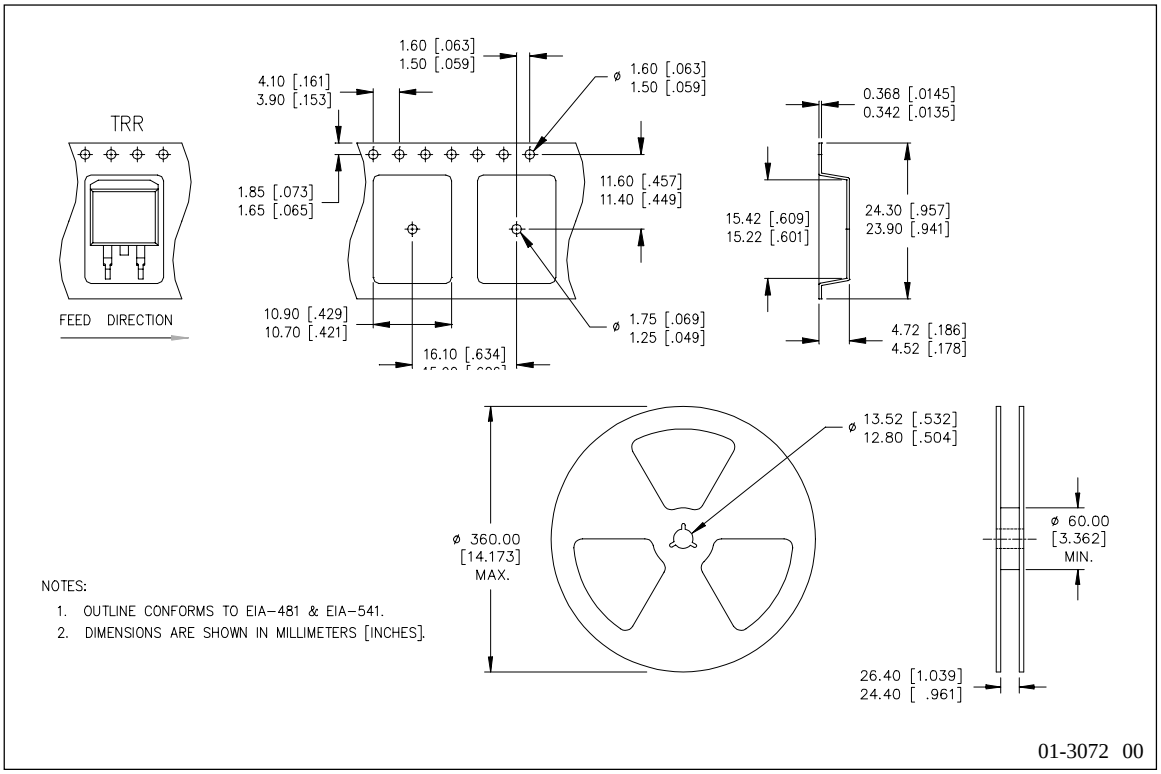
Tape & Reel - D-PAK



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This device was designed and qualified peer automotive level (Q101)

Data and specifications subject to change without notice. 6/1/2004

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Note: For the most current drawings please refer to the IR website at:
http://www.irf.com/package/

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